

2N6671, 2N6672, 2N6673

File Number 1090

## 5-A **SwitchMax** Power Transistors

High-Voltage N-P-N Types for Off-Line Power Supplies and Other High-Voltage Switching Applications

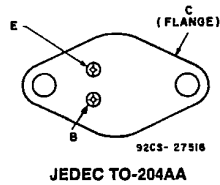
**Features:**

- High-temperature parameters guaranteed
- Fast switching speed
- High voltage ratings:  
 $V_{CEX} = 350\text{ V to }450\text{ V}$
- Low  $V_{CE(sat)}$  at  $I_C = 5\text{ A}$
- Steel hermetic TO-204AA package

**Applications:**

- Off-line power supplies
- High-voltage inverters
- Switching regulators

**TERMINAL DESIGNATIONS**



The RCA-2N6671, 2N6672, and 2N6673\* SwitchMax series of silicon n-p-n power transistors feature high-voltage capability, fast switching speeds, and low saturation voltages, together with high safe-operating-area (SOA) ratings. They are specially designed for use in off-line power supplies and are also well suited for use in a wide range of inverter or converter circuits and pulse-width-modulated regulators. These high-voltage, high-speed tran-

sistors are 100-per-cent tested for parameters that are essential to the design of industrial high-power switching circuits. Switching times, including inductive turn-off time, and saturation voltages are guaranteed at 125°C to provide information necessary for worst-case design.

The RCA-2N6671, 2N6672, and 2N6673 series transistors are supplied in steel JEDEC TO-204AA hermetic packages.

\*Formerly RCA8767, RCA8767A, and RCA8767B, respectively.

**MAXIMUM RATINGS, Absolute-Maximum Values:**

	2N6671	2N6672	2N6673	
* $V_{CEV}$ $V_{BE} = -1.5\text{ V}$ .....	450	550	650	V
* $V_{CEX}$ (Clamped) $V_{BE} = -1.5\text{ V}$ .....	350	400	450	V
* $V_{CEO}$ .....	300	350	400	V
* $V_{EBO}$ .....	8	8	8	V
* $I_{C(sat)}$ .....	5	5	5	A
* $I_C$ .....	8	8	8	A
* $I_{CM}$ .....	10	10	10	A
* $I_B$ .....	4	4	4	A
* $P_T$ $T_C$ up to 25°C .....	150	150	150	W
$T_C$ above 25°C, derate linearly .....	0.86	0.86	0.86	W/°C
* $T_{stg}$ , $T_J$ .....	-65 to 200	-65 to 200	-65 to 200	°C
* $T_L$ At distance $\geq 1/16$ in. (1.58 mm) from seating plane for 10 s max. ....	235	235	235	°C

\* In accordance with JEDEC registration data.

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ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	TEST CONDITIONS				LIMITS						UNITS
	VOLTAGE V <sub>dc</sub>		CURRENT A <sub>dc</sub>		2N6671		2N6672		2N6673		
	V <sub>CE</sub>	V <sub>BE</sub>	I <sub>C</sub>	I <sub>B</sub>	Min.	Max.	Min.	Max.	Min.	Max.	

T<sub>C</sub> = 25°C

* I <sub>CEV</sub>	450 550 650	-1.5 -1.5 -1.5			-	0.1	-	-	-	-	-	-	-	-	-	-	-	-	-	mA	
* I <sub>EBO</sub>		-8	0		-	2	-	2	-	2	-	2	-	2	-	2	-	2	-	2	V
* V <sub>CEO(sus)</sub> <sup>b</sup>			0.2 <sup>a</sup>	0	300	-	350	-	400	-	400	-	400	-	400	-	400	-	400	-	V
* h <sub>FE</sub>	3		5 <sup>a</sup>		10	40	10	40	10	40	10	40	10	40	10	40	10	40	10	40	
* V <sub>BE(sat)</sub>			5 <sup>a</sup>	1	-	1.6	-	1.6	-	1.6	-	1.6	-	1.6	-	1.6	-	1.6	-	1.6	V
* V <sub>CE(sat)</sub>			5 <sup>a</sup>	1	-	1	-	1	-	1	-	1	-	1	-	1	-	1	-	1	V
* V <sub>CEX</sub> <sup>b</sup> (Clamped E <sub>S</sub> /b) L=170 μH, R <sub>BB</sub> =5 Ω		-5 -5	5	1 <sup>e</sup>	350	-	400	-	450	-	450	-	450	-	450	-	450	-	450	-	V
* I <sub>S</sub> /b	25		6		1	-	1	-	1	-	1	-	1	-	1	-	1	-	1	-	s
*  h <sub>fe</sub>   f=5 MHz	10		0.2		3	12	3	12	3	12	3	12	3	12	3	12	3	12	3	12	
* f <sub>T</sub>	10		0.2		15	60	15	60	15	60	15	60	15	60	15	60	15	60	15	60	MHz
* C <sub>obo</sub> f=0.1 MHz	10 <sup>c</sup>				50	300	50	300	50	300	50	300	50	300	50	300	50	300	50	300	pF
* t <sub>d</sub> <sup>d</sup>			5	1	-	0.1	-	0.1	-	0.1	-	0.1	-	0.1	-	0.1	-	0.1	-	0.1	μs
* t <sub>r</sub> <sup>d</sup>			5	1	-	0.5	-	0.5	-	0.5	-	0.5	-	0.5	-	0.5	-	0.5	-	0.5	μs
* t <sub>s</sub> <sup>d</sup>			5	1 <sup>e</sup>	-	2.5	-	2.5	-	2.5	-	2.5	-	2.5	-	2.5	-	2.5	-	2.5	μs
* t <sub>f</sub> <sup>d</sup>			5	1 <sup>e</sup>	-	0.4	-	0.4	-	0.4	-	0.4	-	0.4	-	0.4	-	0.4	-	0.4	μs
* t <sub>c</sub> V <sub>CC</sub> =125 V, L=170 μH, R <sub>C</sub> =25 Ω Collector clamped to V <sub>CEX</sub>			5	1 <sup>e</sup>	-	0.4	-	0.4	-	0.4	-	0.4	-	0.4	-	0.4	-	0.4	-	0.4	μs

T<sub>C</sub> = 125°C

* I <sub>CEV</sub>	450 550 650	-1.5 -1.5 -1.5			-	1	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	mA
* V <sub>CE(sat)</sub>			5 <sup>a</sup>	1	-	2	-	2	-	2	-	2	-	2	-	2	-	2	-	2	V	
* t <sub>r</sub> <sup>d</sup>			5	1	-	0.8	-	0.8	-	0.8	-	0.8	-	0.8	-	0.8	-	0.8	-	0.8	μs	
* t <sub>s</sub> <sup>d</sup>			5	1 <sup>e</sup>	-	4	-	4	-	4	-	4	-	4	-	4	-	4	-	4	μs	
* t <sub>f</sub> <sup>d</sup>			5	1 <sup>e</sup>	-	0.8	-	0.8	-	0.8	-	0.8	-	0.8	-	0.8	-	0.8	-	0.8	μs	
* t <sub>c</sub> V <sub>CC</sub> =125 V, L=170 μH, R <sub>C</sub> =25 Ω Collector clamped to V <sub>CEX</sub>			5	1 <sup>e</sup>	-	0.8	-	0.8	-	0.8	-	0.8	-	0.8	-	0.8	-	0.8	-	0.8	μs	

* R <sub>θJC</sub>					-	1.17	-	1.17	-	1.17	-	1.17	-	1.17	-	1.17	-	1.17	-	1.17	°C/W
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\* In accordance with JEDEC registration data.  
<sup>a</sup> Pulsed: pulse duration = 300 μs, duty factor ≤ 2%.  
<sup>b</sup> CAUTION: The sustaining voltage V<sub>CEO(sus)</sub> and V<sub>CEX</sub> MUST NOT be measured on a curve tracer.  
<sup>c</sup> V<sub>CB</sub> value.  
<sup>d</sup> V<sub>CC</sub> = 125 V, t<sub>p</sub> = 20 μs.  
<sup>e</sup> I<sub>B1</sub> = -I<sub>B2</sub>.

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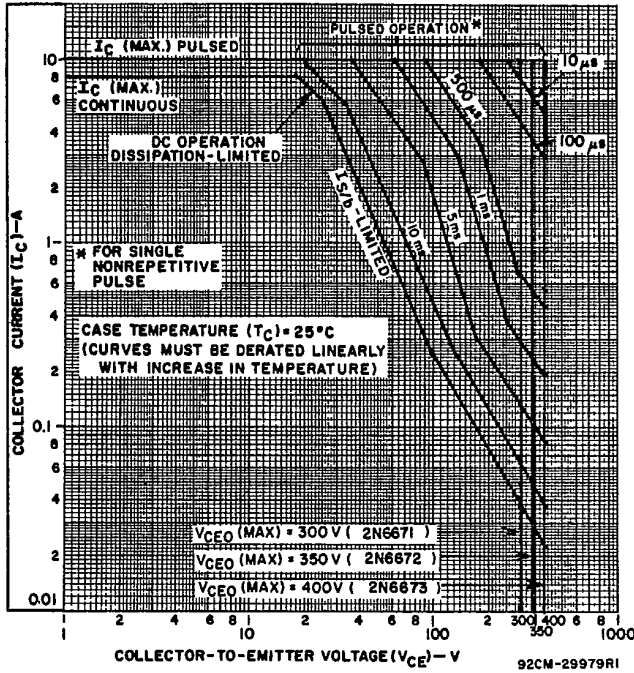


Fig. 1 — Maximum operating areas for all types ( $T_c = 25^\circ C$ ).

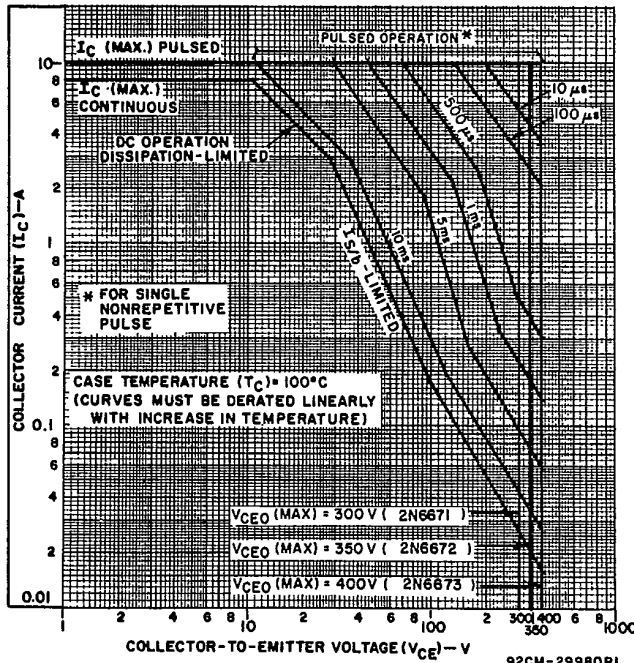


Fig. 2 — Maximum operating areas for all types ( $T_c = 100^\circ C$ ).

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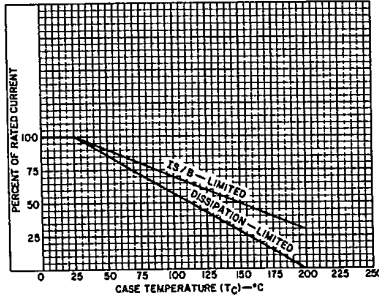


Fig. 3 - Dissipation and  $I_{SIB}$  derating curves for all types.

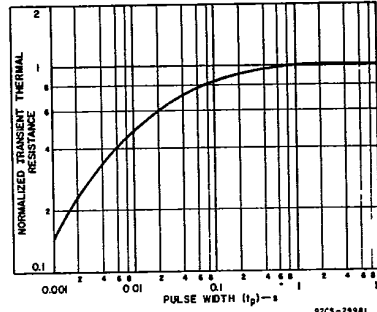


Fig. 4 - Typical thermal-response characteristic for all types.

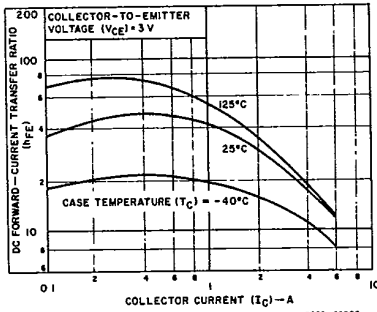


Fig. 5 - Typical dc beta characteristics for all types.

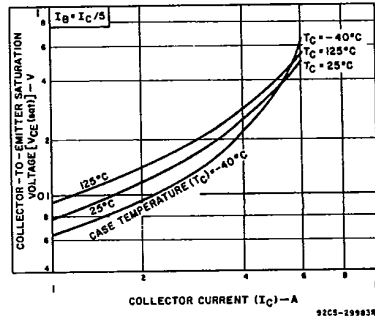


Fig. 6 - Typical collector-to-emitter saturation voltage as a function of collector current for all types.

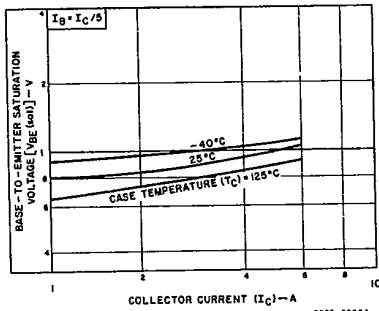


Fig. 7 - Typical base-to-emitter saturation voltage as a function of collector current for all types.

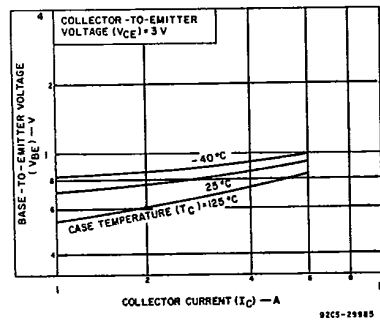


Fig. 8 - Typical base-to-emitter voltage as a function of collector current for all types.

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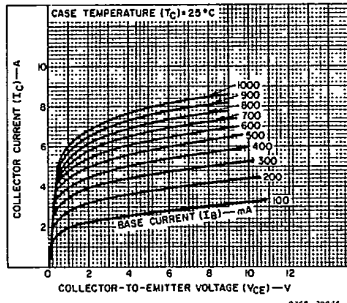


Fig. 9 — Typical output characteristics for all types.

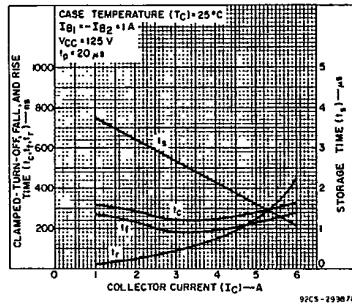


Fig. 10 — Typical saturated switching time characteristics for all types.

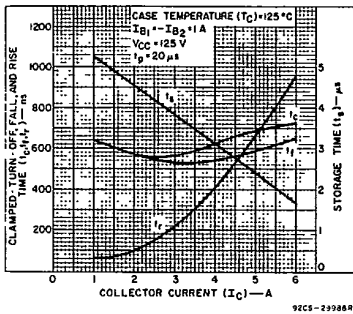


Fig. 11 — Typical saturated switching time characteristics for all types.

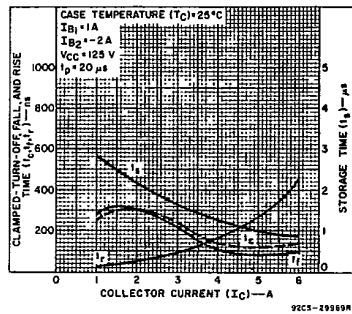


Fig. 12 — Typical saturated switching time characteristics for all types.

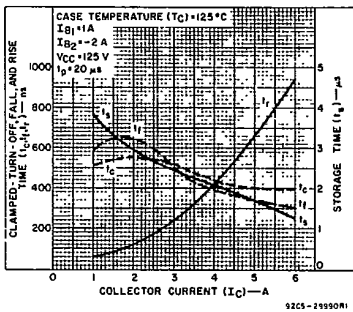


Fig. 13 — Typical saturated switching time characteristics for all types.

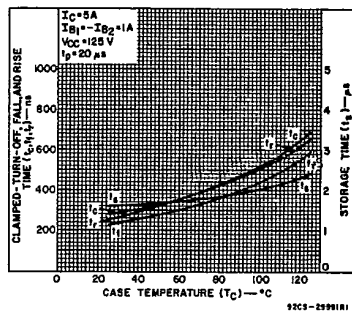


Fig. 14 — Typical saturated switching time characteristics as a function of

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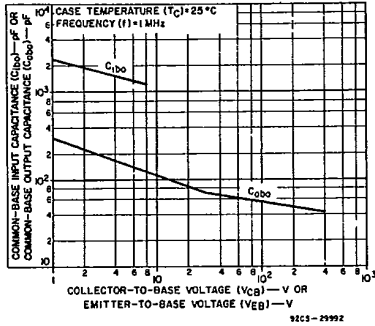


Fig. 15 — Typical common-base input or output capacitance characteristics as a function of collector-to-base voltage or emitter-to-base voltage for all types.

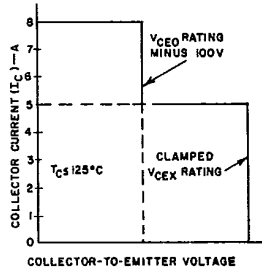


Fig. 16 — Maximum operating conditions for switching between saturation and cutoff.

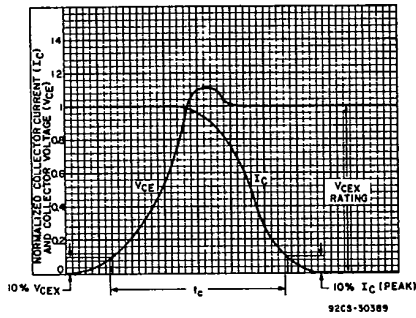


Fig. 17 — Oscilloscope display for measurement of clamped induction switching time (t<sub>c</sub>).

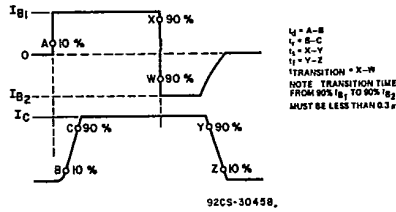


Fig. 18 — Phase relationship between input and output currents showing reference points for specification of switching times.

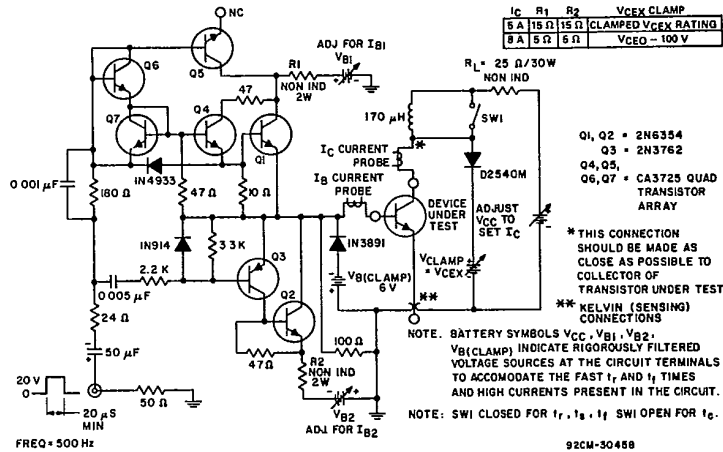


Fig. 19 — Circuit for measuring switching times.